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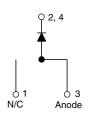
Vishay Semiconductors

HALOGEN

FREE

HEXFRED® Ultrafast Soft Recovery Diode, 8 A





PRIMARY CHARACTERISTICS								
I _{F(AV)}	8 A							
V_{R}	600 V							
V _F at I _F	1.4 V							
t _{rr} typ.	18 ns							
T _J max.	150 °C							
Package	DPAK (TO-252AA)							
Circuit configuration	Single							

FEATURES

- · Ultrafast recovery time
- Ultrasoft recovery
- Very low I_{RRM}
- Very low Q_{rr}
- Guaranteed avalanche
- · Specified at operating conditions
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

BENEFITS

- Reduced RFI and EMI
- Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- Reduced parts count

DESCRIPTION / APPLICATIONS

These diodes are optimized to reduce losses and EMI / RFI in high frequency power conditioning systems. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for freewheeling, flyback, power converters, motor drives, and other applications where high speed and reduced switching losses are design requirements.

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS						
Cathode to anode voltage	V_{RRM}		600	V						
Maximum continuous forward current	I _F	T _C = 100 °C	8							
Single pulse forward current	I _{FSM}		60	Α						
Peak repetitive forward current	I _{FRM}		24							
Maximum power dissipation	P _D	T _C = 100 °C	14	W						
Operating junction and storage temperature range	T _J , T _{Stg}		-55 to +150	°C						

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V _{BR} , V _R	Ι _R = 100 μΑ	600	-	-				
Forward voltage		I _F = 8 A		-	1.4	1.7	V		
	V_{F}	I _F = 16 A	See fig. 1	-	1.7	2.1			
		I _F = 8 A, T _J = 125 °C		-	1.4	1.7			
Maximum reverse		$V_R = V_R$ rated		-	0.3	5.0			
leakage current	I _R	$T_J = 125 ^{\circ}\text{C}, V_R = 0.8 ^{\circ}\text{X} ^{\circ}\text{V}_R ^{\circ}\text{rated}$		-	100	500	μΑ		
Junction capacitance	C _T	V _R = 200 V See fig. 3		-	10	25	pF		
Series inductance	L _S	Measured lead to lead 5 mm from pa	ckage body	-	8.0	-	nH		

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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS			
		$I_F = 1.0 \text{ A}, dI_F/dt = 200$	$I_F = 1.0 \text{ A}, dI_F/dt = 200 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$			-			
Reverse recovery time	t _{rr}	T _J = 25 °C		-	37	55	ns		
		T _J = 125 °C	I _F = 8 A dI _F /dt = 200 A/μs V _R = 200 V	-	55	90			
Peak recovery current	I _{RRM}	T _J = 25 °C		-	3.5	5.0	A nC		
		T _J = 125 °C		-	4.5	8.0			
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	65	138			
		T _J = 125 °C		-	124	360	IIC		
Rate of fall of recovery current	dI _{(rec)M} /dt	T _J = 25 °C		-	240	-	Λ/μο		
		T _J = 125 °C		-	210	-	- A/μs		

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	150	°C			
Thermal resistance, junction to case	R _{thJC}		-	-	3.5	°C/W			
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	80	C/VV			
Weight			-	2.0	-	g			
Weight			-	0.07	-	OZ.			
Marking device		Case style DPAK (TO-252AA)		HFA08	SD60S				



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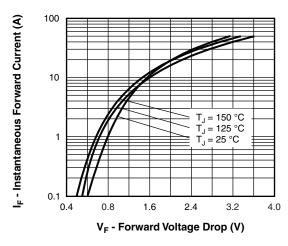


Fig. 1 - Typical Forward Voltage Drop Characteristics

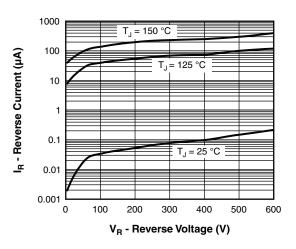


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

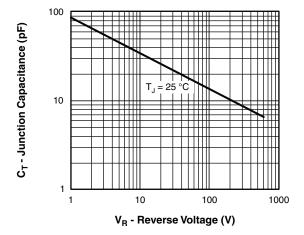


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

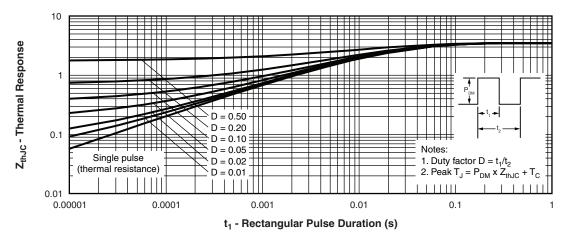


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics





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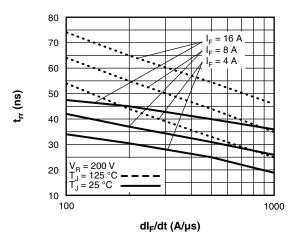


Fig. 5 - Typical Reverse Recovery Time vs. dl_F/dt

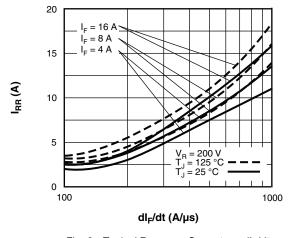


Fig. 6 - Typical Recovery Current vs. dI_F/dt

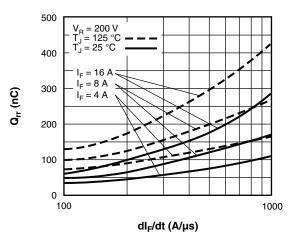


Fig. 7 - Typical Stored Charge vs. dl_F/dt

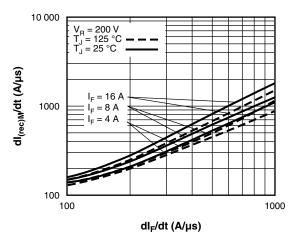


Fig. 8 - Typical $dI_{(rec)M}/dt$ vs. dI_F/dt

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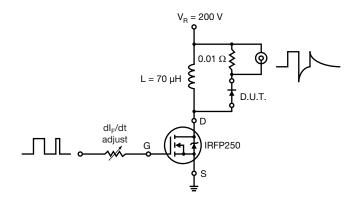
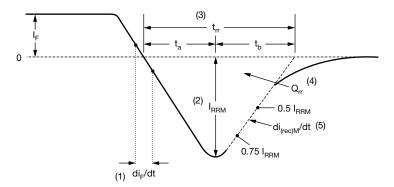


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_F$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) ${\rm Q_{rr}}$ area under curve defined by ${\rm t_{rr}}$ and ${\rm I_{RRM}}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) di_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

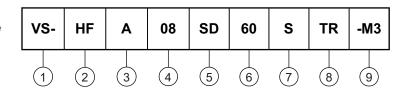
Fig. 10 - Reverse Recovery Waveform and Definitions



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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

- HEXFRED® family

3 - Electron irradiated

Current rating (08 = 8 A)

5 - D-PAK

6 - Voltage rating (60 = 600 V)

7 - S = D-PAK

- • TR = tape and reel

• R = tape and reel (right oriented)

• L = tape and reel (left oriented)

9 - Environmental digit:

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-HFA08SD60S-M3	75	3000	Antistatic plastic tube						
VS-HFA08SD60STR-M3	2000	2000	13" diameter reel						
VS-HFA08SD60SL-M3	3000	3000	13" diameter reel						
VS-HFA08SD60SR-M3	3000	3000	13" diameter reel						

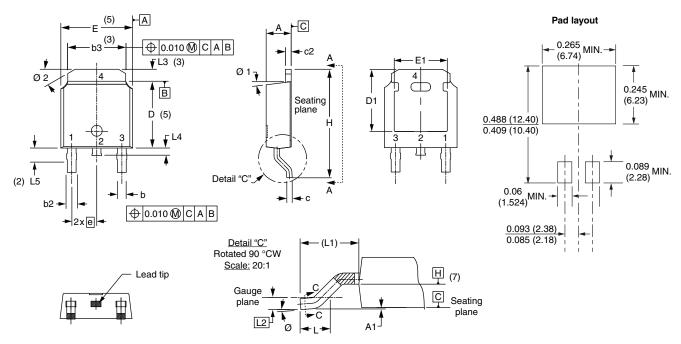
LINKS TO RELATED DOCUMENTS						
Dimensions <u>www.vishay.com/doc?95627</u>						
Part marking information	www.vishay.com/doc?95176					
Packaging information	www.vishay.com/doc?95033					



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D-PAK (TO-252AA) "M"

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		ETERS INCHES		NOTES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC	
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410	
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070	
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.	
b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	0.020 BSC		
С	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050	3
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040	
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060	2
D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°	
Е	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°	
E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC® outline TO-252AA

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